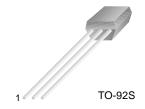


## KSC2784

### **Audio Frequency Low Noise Amplifier**

Complement to KSA1174



1.Emitter 2. Collector 3. Base

## **NPN Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	120	V
V <sub>CEO</sub>	Collector-Emitter Voltage	120	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	50	mA
I <sub>B</sub>	Base Current	10	mA
P <sub>C</sub>	Collector Power Dissipation	300	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

## **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =120V, I <sub>E</sub> =0			50	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ =5V, $I_{C}$ =0			50	nA
h <sub>FE1</sub>	DC Current Gain	V <sub>CE</sub> =6V, I <sub>C</sub> =0.1mA V <sub>CE</sub> =6V, I <sub>C</sub> =1mA	150 200	580 600	1200	
V <sub>BE</sub> (on)	Base Emitter On Voltage	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA	0.55	0.59	0.65	V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA		0.07	0.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA	50	110		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =30V, I <sub>E</sub> =0, f=1MHz		1.6	2.5	pF
NL	Noise Level			25	40	mV

## h<sub>FE2</sub> Classification

Classification	Р	F	E	U
h <sub>FE2</sub>	200 ~ 400	300 ~ 600	400 ~ 800	600 ~ 1200

# **Typical Characteristics**

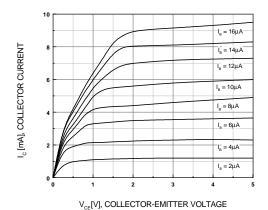


Figure 1. Static Characteristics

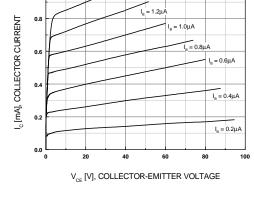


Figure 2. Static Characteristics

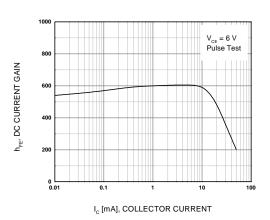


Figure 3. DC Currnet Gain

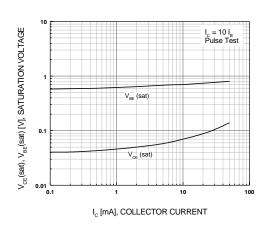


Figure 4. Saturation Voltage

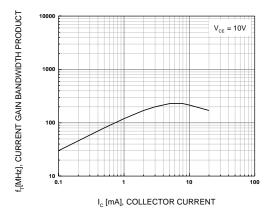


Figure 5. f<sub>T</sub> - I<sub>C</sub>

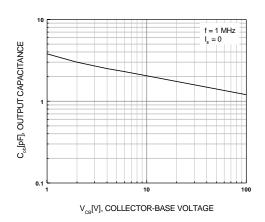
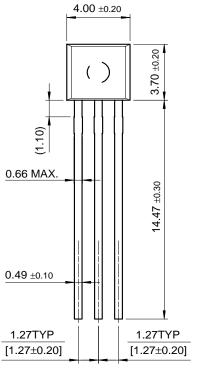


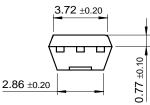
Figure 6. Output Capacitance

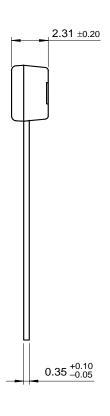
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## **Package Dimensions**

**TO-92S** 







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	$VCX^{TM}$
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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